

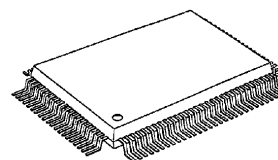
CMOS 8-Bit Microcontroller

TMP88PU77F

The TMP88PU77 are the high-speed and high performance 8-bit single chip microcomputers which built in a program storage area (96 Kbyte) and the One-Time PROM of vector table storage area (256 byte). The TMP88PU77 is pin compatible with the TMP88CP77/S77. The operations possible with the TMP88PU77 can be performed by writing programs to PROM. The TMP88PU77 can write and verify in the same way as the TC571000 an EPROM programmer.

Part No.	OTP	RAM	Package	Adaptor Socket
TMP88PU77F	96 Kbyte + 256 byte	3 Kbyte	P-QFP100-1420-0.65A	BM11150

P-QFP100-1420-0.65A

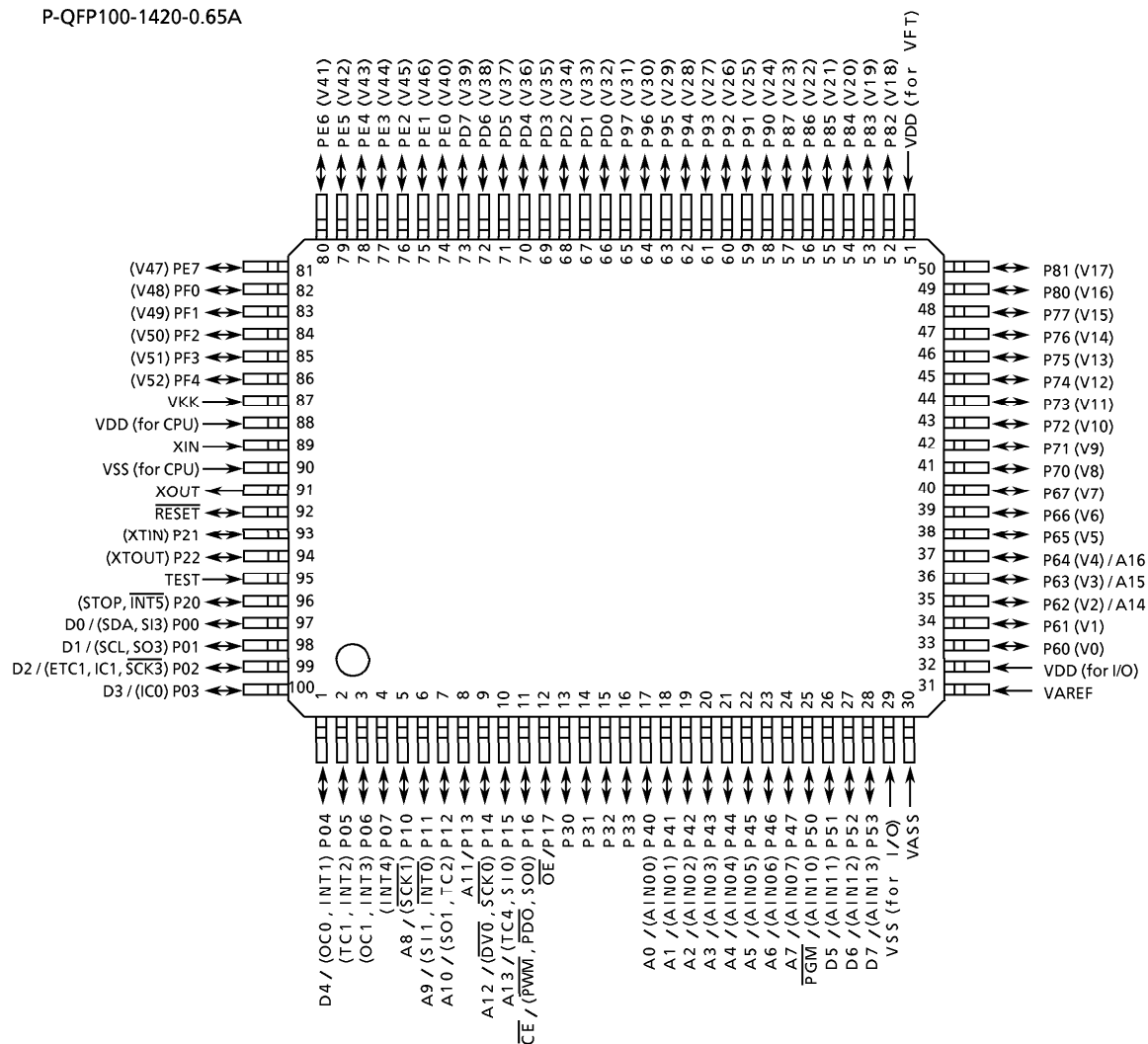
TMP88CP77F
TMP88CS77F
TMP88PU77F

980910EBP1

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Pin Assignments (Top View)

P-QFP100-1420-0.65A



Pin Function

The TMP88PU77 has two modes: MCU and PROM.

(1) MCU mode

In this mode, the TMP88PU77 is pin compatible with the TMP88CP77/S77 (fix the TEST pin at low level).

(2) PROM mode

Pin Name (PROM mode)	Input/Output	Functions	Pin Name (MCU mode)
A16	Input	PROM address inputs	P64
A15 to A8			P63, P62, P15 to P10
A7 to A0			P47 to P40
D7 to D0	I/O	PROM data input/outputs	P53 to P51, P04 to P00
$\overline{\text{CE}}$	Input	Chip enable signal input (active low)	P16
$\overline{\text{OE}}$		Output enable signal input (active low)	P17
$\overline{\text{PGM}}$		Program mode single input	P50
VPP	Power supply	+ 12.75 V / 5 V (Program supply voltage)	TEST
VCC		+ 6.25 V / 5 V	VDD
GND		0 V	VSS
P07 to P05	Input	Pull-up with resistance for input processing	
P33 to P30			
P60		PROM mode setting pin. Be fixed at high level.	
P21			
P67, P66, P61		PROM mode setting pin. Be fixed at low level.	
PF4 to PF0, PE7 to PE0			
$\overline{\text{RESET}}$			
P65	Output	Open	
P77 to P70			
P87 to P80			
P97 to P90			
PD7 to PD0			
XIN	Input	Connect an 8 MHz oscillator to stabilize the internal state.	
XOUT	Output		
VAREF	Power supply	0 V (GND)	
VASS			
VKK		Open	

Operational Description

The configuration and functions of the TMP88PU77 are the same as those of the TMP88CP77/S77, except in that a one-time PROM is used instead of an on-chip mask ROM.

1. Operating Mode

The TMP88PU77 has two modes: MCU and PROM.

1.1 MCU Mode

The MCU mode is activated by fixing the TEST / VPP pin at low level.

In the MCU mode, operation is the same as with the TMP88CP77/S77 (the TEST / VPP pin cannot be used open because it has no built-in pull-down resistance).

1.1.1 Program memory

The TMP88PU77 has a 96 Kbyte (addresses 04000_H to 1BFFF_H in the MCU mode, addresses 00000_H to 17FFF_H in the PROM mode) of program storage area and 256 byte (addresses FFF00 to FFFFF_H in the MCU mode, addresses 1FF00 to 1FFFF_H in the PROM mode) one-time PROM of vector table storage area.

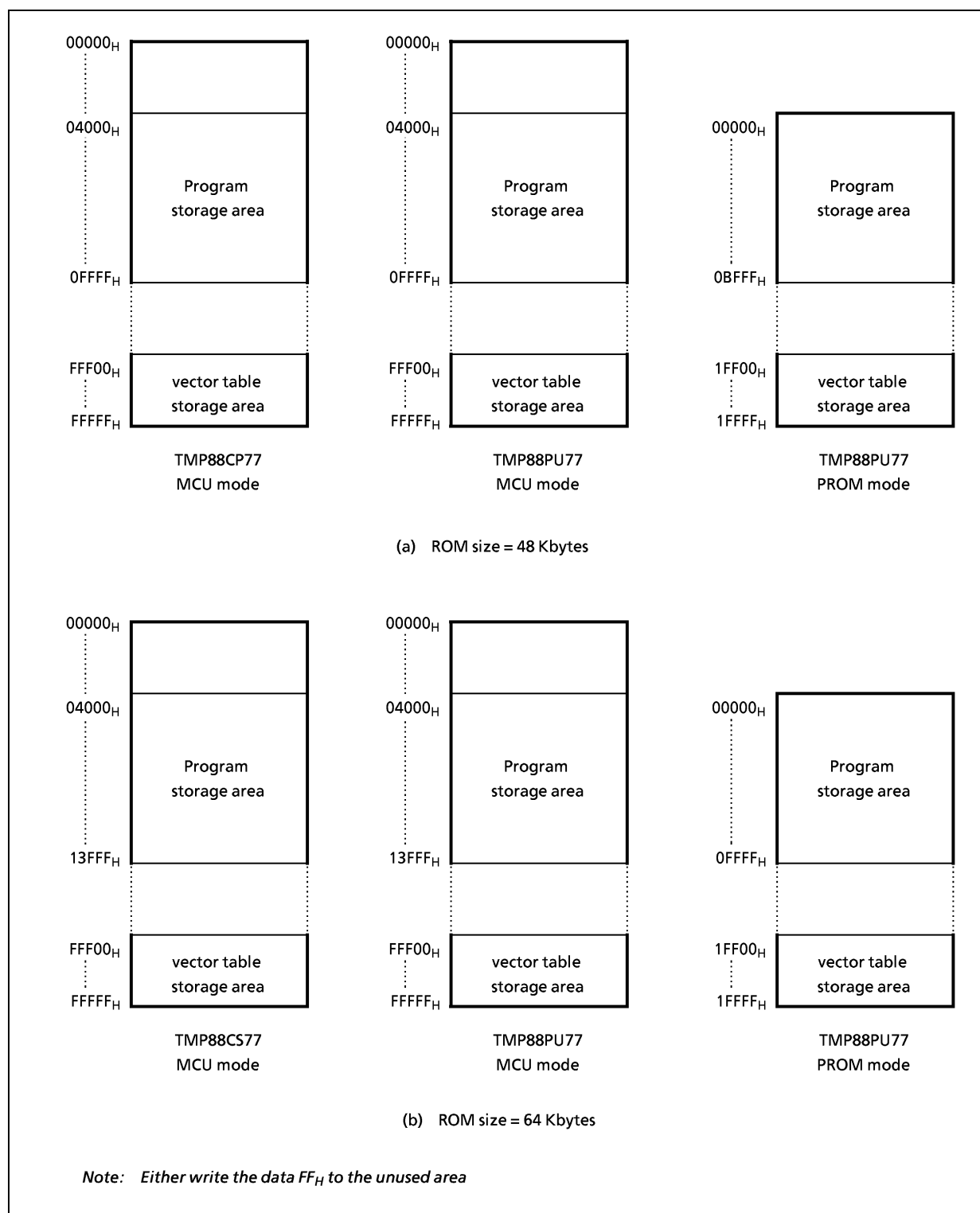


Figure 1-1. Program Storage Area

1.1.2 Data memory

The TMP88PU77 has an on-chip 3 Kbyte data memory (static RAM).

1.1.3 Input/output circuitry

(1) Control pins

The control pins of the TMP88PU77 are the same as those of the TMP88CP77/S77 except that the TEST pin has no built-in pull-down resistance.

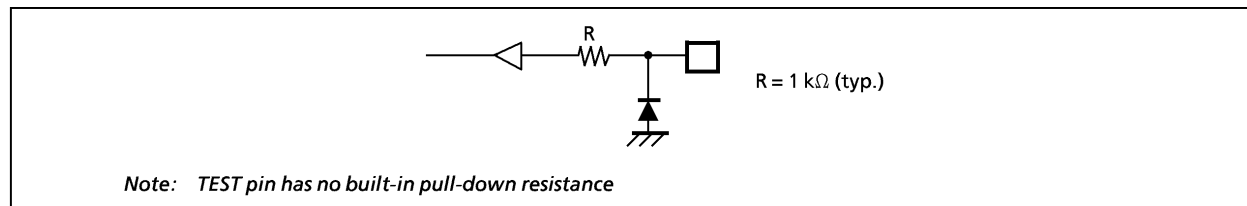


Figure 1-2. TEST Pin

(2) I/O ports

The I/O circuitries of TMP88PU77 I/O ports are the same as the code A type I/O circuitries of the TMP88CP77/S77.

1.2 PROM Mode

The PROM mode is activated by setting shown in Figure 1-2. The PROM mode is used to write and verify programs with a general-purpose PROM programmer. The high-speed programming mode can be used for program operation.

The TMP88PU77 is not supported an electric signature mode, so the ROM type must be set to TC571000. Set the adaptor socket switch to "N".

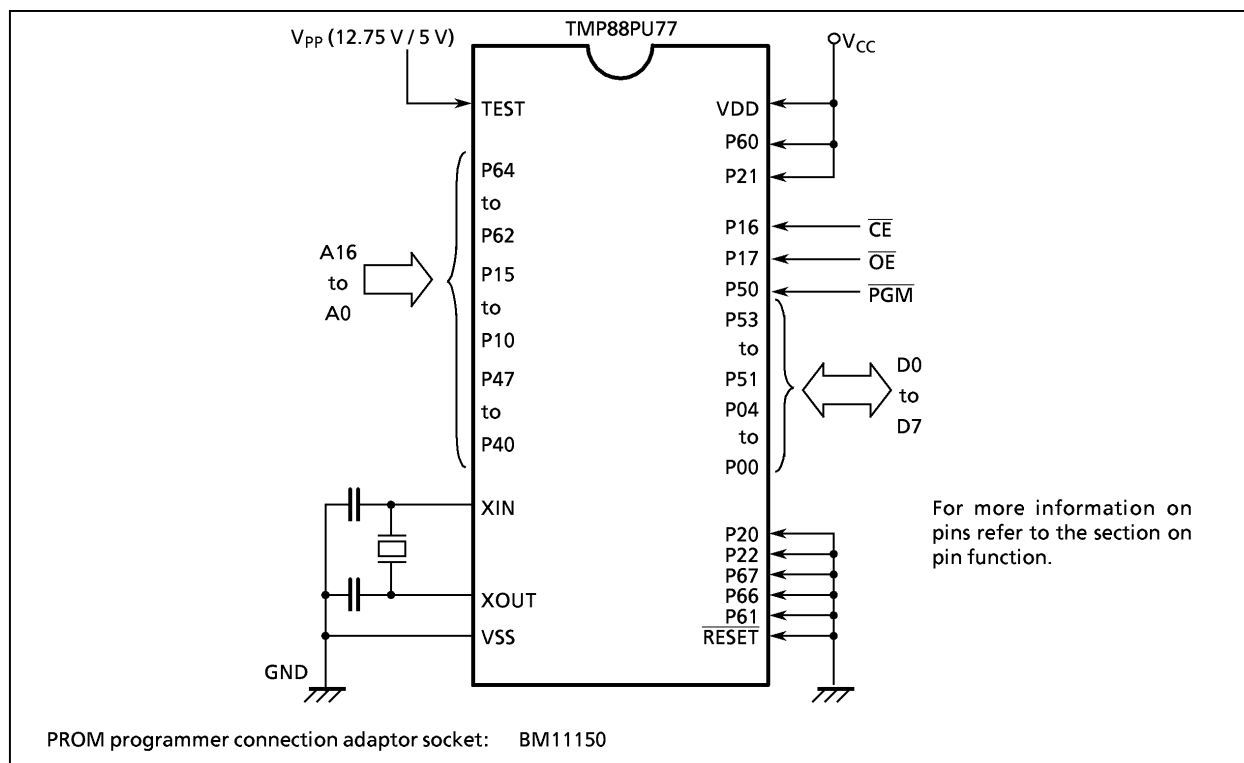


Figure 1-3. Setting for PROM Mode

1.2.1 Programming flowchart (High-speed programming)

The high-speed programming mode is achieved by applying the program voltage (+ 12.75 V) to the V_{pp} pin when $V_{cc} = 6.25$ V. After the address and input data are stable, the data is programmed by applying a single 0.1ms program pulse to the \overline{CE} input. The programmed data is verified. If incorrect, another 0.1ms program pulse is applied and then the programmed data is verified. This process should be repeated (up to 25 times) until the program operates correctly. After that, change the address and input data, and program as before. When programming has been completed, the data in all addresses should be verified with $V_{cc} = V_{pp} = 5$ V.

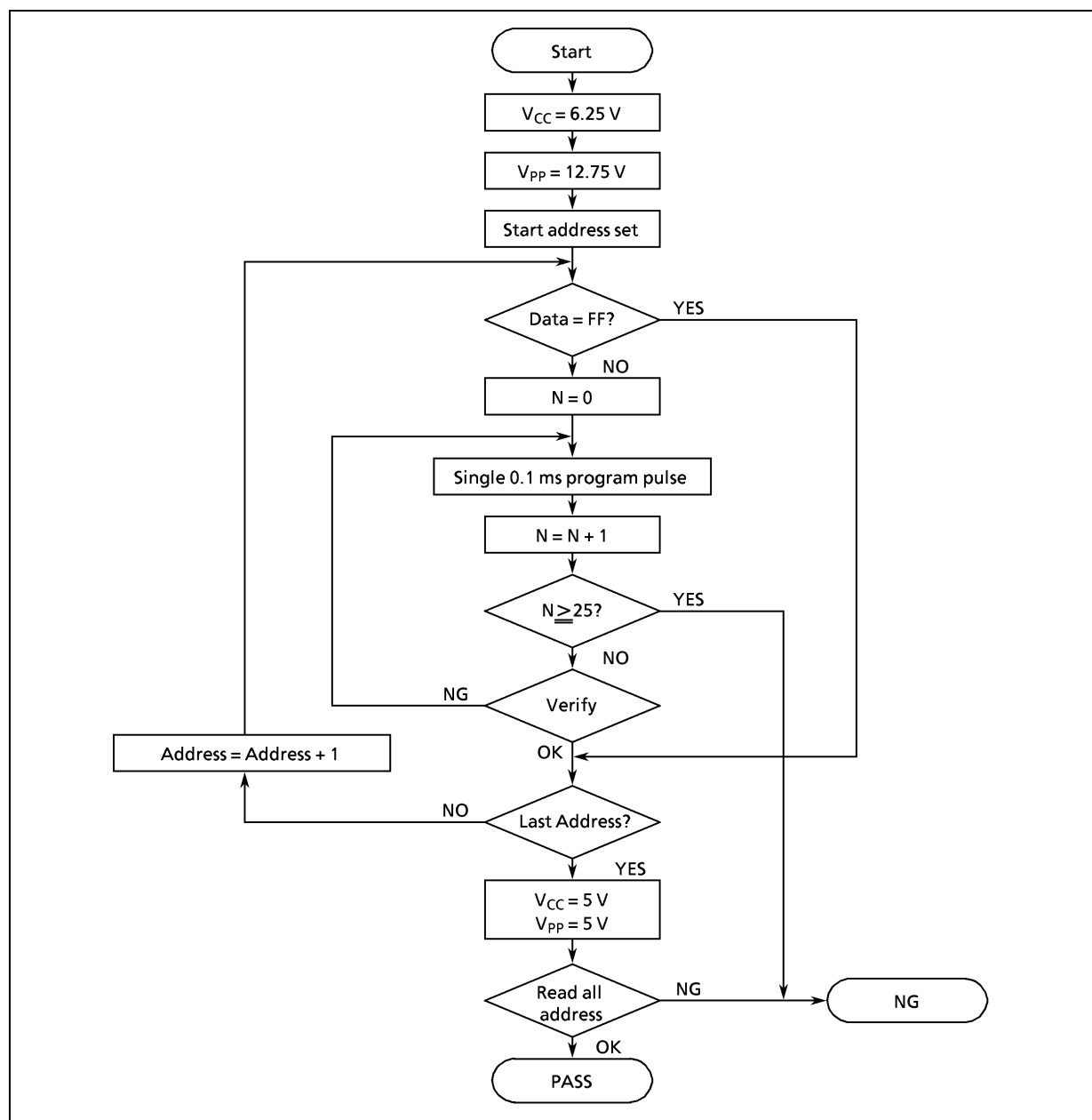


Figure 1-4. Flowchart of High-speed Programming

1.2.2 Writing method for general-purpose PROM program

- (1) Adapters
BM11150
- (2) Adapter setting
Switch (SW1) is set to side N.
- (3) PROM programmer specifying
 - i) PROM type is specified to TC571000.
Writing voltage: 12.75 V (high-speed program)
 - ii) Data transfer (copy) (Note 1)
In TMP88PU77, EPROM is within the addresses 00000_H to 17FFF_H and 1FF00_H to 1FFFF_H. Data is required to be transferred (copied) to the addresses where it is possible to write. The program area in MCU mode and PROM mode is referred to "Program memory area" in Figure 1-1.

Ex. In the block transfer (copy) mode, executed as below.
Program area : transferred addresses 04000_H to 1BFFF_H to addresses 00000 to 17FFF_H
Vector area : transferred addresses FFF00_H to FFFFF_H to 1FF00 to 1FFFF_H
 - iii) Writing address is specified. (Note 1)
Start address : 00000_H
End address : 1FFFF_H
- (4) Writing
Writing/Verifying is required to be executed in accordance with PROM programmer operating procedure.

Note 1: The specifying method is referred to the PROM programmer description. Either write the data FF_H to the unused area or set the PROM programmer to access only the program storage area.

Note 2: When MCU is set to an adapter or the adapter is set to PROM programmer, a position of pin 1 must be adjusted. If the setting is reversed, MCU, the adapter and PROM program is damaged.

Note 3: The TMP88PU77 does not support the electric signature mode (hereinafter referred to as "signature"). If the signature is used in PROM program, a device is damaged due to applying 12 V ± 0.5 V to the address pin 9 (A9). The signature must not be used.

Electrical Characteristics

Absolute Maximum Ratings		(V _{SS} = 0 V)		
Parameter	Symbol	Pins	Ratings	Unit
Supply Voltage	V _{DD}		– 0.3 to 6.5	V
Program Voltage	V _{PP}	TEST/VPP	– 0.3 to 13.0	V
Input Voltage	V _{IN1}	P1, P2, P3, P4, P5, XOUT, RESET	– 0.3 to V _{DD} + 0.3	V
	V _{IN2}	P0 port	– 0.3 to 5.5 V	
Output Voltage	V _{OUT1}	P1, P2, P3, P4, P5, XOUT, RESET	– 0.3 to V _{DD} + 0.3	V
	V _{OUT2}	P0 port	– 0.3 to 5.5 V	
	V _{OUT3}	Source open drain ports	V _{DD} – 40 to V _{DD} + 0.3	
Output Current (Per 1 pin)	I _{OUT1}	P0, P1, P2, P3, P4, P5 ports	3.2	mA
	I _{OUT2}	P6, P7, P80, 81 Ports	– 25	
	I _{OUT3}	P82 to P87, P9, PD, PE, PF ports	– 12	
Output Current (Total)	Σ I _{OUT1}	P1, P3, P4, P5 ports	– 40	mA
	Σ I _{OUT2}	P0, P1, P2, P3, P4, P5 ports	60	
	Σ I _{OUT3}	P6, P7, P8, P9, PD, PE, PF ports	– 120	
Power Dissipation [Topr = 25°C]	PD	note	1200	mW
Soldering Temperature (time)	Tsld		260 (10 s)	°C
Storage Temperature	Tstg		– 55 to 125	°C
Operating Temperature	Topr		– 30 to 70	°C

Note 1: The absolute maximum ratings are rated values which must not be exceeded during operation, even for an instant. Any one of the ratings must not be exceeded. If any absolute maximum rating is exceeded, a device may break down or its performance may be degraded, causing it to catch fire or explode resulting in injury to the user. Thus, when designing products which include this device, ensure that no absolute maximum rating value will ever be exceeded.

Note 2: Power Dissipation (PD) ; For PD, it is necessary to decrease -14.3 mW/°C. (Reference to TMP88CP77/S77)

Recommended Operating Conditions		(V _{SS} = 0 V, Topr = – 30 to 70°C)				
Parameter	Symbol	Pins	Conditions	Min	Max	Unit
Supply Voltage	V _{DD}		f _c = 12.5 MHz NORMAL1, 2 modes	4.5	5.5	V
			IDLE1, 2 modes			
			f _s = 32.768 kHz SLOW mode			
			SLEEP mode	2.0		
Input High Voltage	V _{IH1}	Except hysteresis input	V _{DD} ≥ 4.5 V	V _{DD} × 0.70	V _{DD}	V
	V _{IH2}	Hysteresis input		V _{DD} × 0.75		
	V _{IH3}		V _{DD} < 4.5 V	V _{DD} × 0.90		
Input Low Voltage	V _{IL1}	Except hysteresis input	V _{DD} ≥ 4.5 V	0	V _{DD} × 0.30	V
	V _{IL2}	Hysteresis input			V _{DD} × 0.25	
	V _{IL3}		V _{DD} < 4.5 V		V _{DD} × 0.10	
Clock Frequency	f _c	XIN, XOUT	V _{DD} = 4.5 V to 5.5 V	1.0	12.5	MHz
	f _s	XTIN, XTOUT	V _{DD} = 2.7 V to 5.5 V	30.0	34.0	kHz

Note: The recommended operating conditions for a device are operating conditions under which it can be guaranteed that the device will operate as specified. If the device is used under operating conditions other than the recommended operating conditions (supply voltage, operating temperature range, specified AC/DC values etc.), malfunction may occur. Thus, when designing products which include this device, ensure that the recommended operating conditions for the device are always adhered to.

D.C. Characteristics			(V _{SS} = 0 V, Topr = – 30 to 70°C)				
Parameter	Symbol	Pins	Conditions	Min	Typ.	Max	Unit
Hysteresis Voltage	V _{HS}	Hysteresis input		–	0.9	–	V
Input Current	I _{IN1}	TEST	V _{DD} = 5.5 V V _{IN} = 5.5 V / 0 V	–	–	± 2	μA
	I _{IN2}	Open drain ports, Tri-state ports					
	I _{IN3}	RESET, STOP					
	I _{IN4}	PD, PE, PF ports (Note3)				80	
Input Resistance	R _{IN3}	RESET		100	220	450	kΩ
Pull-down Resistance	R _K	Source open drain ports	V _{DD} = 5.5 V, V _{KK} = – 30 V	50	80	110	
Output Leakage Current	I _{LO1}	Sink open drain ports	V _{DD} = 5.5 V, V _{OUT} = 5.5 V	–	–	2	μA
	I _{LO2}	Source open drain ports	V _{DD} = 5.5 V, V _{OUT} = – 32 V	–	–	– 2	
	I _{LO3}	Tri-state ports	V _{DD} = 5.5 V, V _{OUT} = 5.5 V / 0 V	–	–	2	
Output High Voltage	V _{OH2}	Tri-state ports	V _{DD} = 4.5 V, I _{OH} = – 0.7 mA	4.1	–	–	V
Output Low Voltage	V _{OL}	Except XOUT	V _{DD} = 4.5 V, I _{OL} = 1.6 mA	–	–	0.4	V
Output High current	I _{OH1}	P6, P7, P80, P81 port	V _{DD} = 4.5 V, V _{OH} = 2.4 V	–	– 30	–	mA
	I _{OH2}	P82 to P87, P9, PD, PE, PF ports		–	– 15	–	
Supply Current in NORMAL 1, 2 modes	I _{DD}		V _{DD} = 5.5 V V _{IN} = 5.3 V / 0.2 V f _c = 12.5 MHz f _s = 32.768 kHz	–	15	22	mA
Supply Current in IDLE 1, 2 modes				–	6	12	
Supply Current in SLOW mode			V _{DD} = 3.0 V V _{IN} = 2.8 V / 0.2 V f _s = 32.768 kHz	–	30	60	μA
Supply Current in SLEEP mode			–	15	30		
Supply Current in STOP mode			V _{DD} = 5.5 V V _{IN} = 5.3 V / 0.2 V	–	0.5	10	
Note 1: Typical values show those at Topr = 25°C, V _{DD} = 5 V.							
Note 2: Input Current I _{IN1} , I _{IN3} ; The current through resistor is not included, when the input resistor (pull-up/pull-down) is contained.							
Note 3: Input Current I _{IN4} ; The current when the pull-down register (R _k) is not connected by the mask option.							

AD Conversion Characteristics		(V _{SS} = 0 V, V _{DD} = 4.5 to 5.5 V, T _{opr} = – 30 to 70°C)				
Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
Analog Reference Voltage	V _{AREF}		4.5	–	V _{DD}	V
	V _{ASS}		V _{SS}			
Analog Reference Voltage Range	V _{AIN}		V _{ASS}	–	V _{AREF}	V
Analog Input Voltage	I _{REF}	V _{AREF} = 5.5 V, V _{ASS} = 0.0 V	–	0.5	1.0	mA
Nonlinearity Error		V _{DD} = 5.0 V, V _{SS} = 0.0 V V _{AREF} = 5.000 V V _{ASS} = 0.000 V	–	–	± 1	LSB
Zero Point Error			–	–	± 1	
Full Scale Error			–	–	± 1	
Total Error			–	–	± 2	
Note: Quantizing error is not contained in those errors.						

AC Characteristics

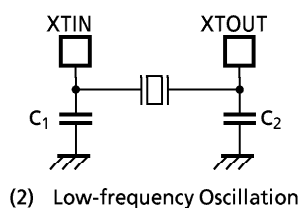
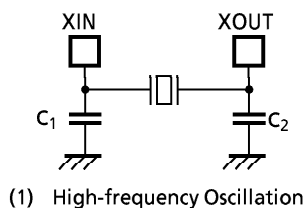
 $(V_{SS} = 0\text{ V}, V_{DD} = 4.5\text{ to }5.5\text{ V}, T_{opr} = -30\text{ to }70^{\circ}\text{C})$

Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
Machine Cycle Time	tcy	In NORMAL1, 2 modes	0.32	–	10	μ S
		In IDLE1, 2 modes				
		In SLOW mode	117.6	–	133.3	
		In SLEEP mode				
High Level Clock Pulse Width	t _{WCH}	For external clock operation (XIN input), fc = 12.5 MHz	32	–	–	ns
Low Level Clock Pulse Width	t _{WCL}					
High Level Clock Pulse Width	t _{WSH}	For external clock operation (XTIN input), fs = 32.768 kHz	15.2	–	–	μ S
Low Level Clock Pulse Width	t _{WSL}					

Recommended Oscillating Conditions

 $(V_{SS} = 0\text{ V}, V_{DD} = 4.5\text{ to }5.5\text{ V}, T_{opr} = -30\text{ to }70^{\circ}\text{C})$

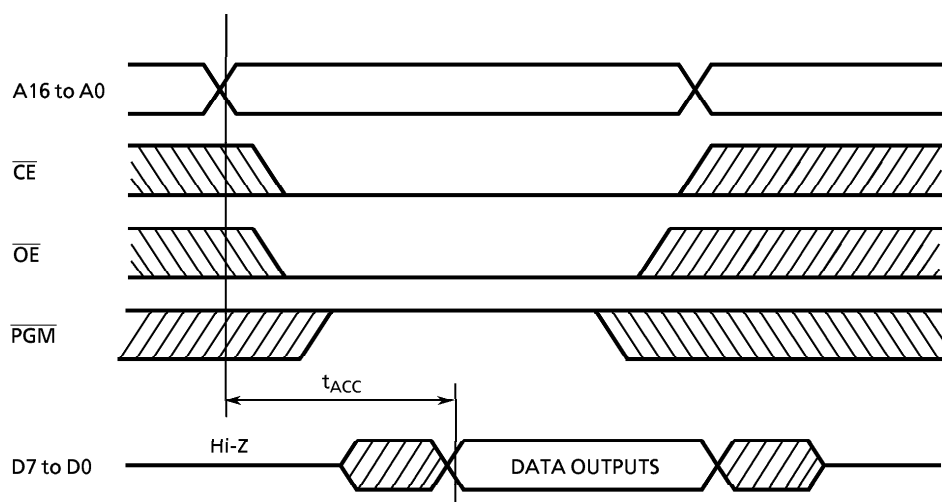
Parameter	Oscillator	Oscillation Frequency	Recommended Oscillator	Recommended Constant	
				C ₁	C ₂
High-frequency Oscillation	Ceramic Resonator	12.5 MHz	Murata CSA12.5MTZ	30 pF	30 pF
		8 MHz	Murata CSA8.00MTZ	30 pF	30 pF
	Crystal Oscillator	12.5 MHz	NDK AT-51	10 pF	10 pF
Low-frequency Oscillation	Crystal Oscillator	32.768 kHz	NDK MX-38T	15 pF	15 pF



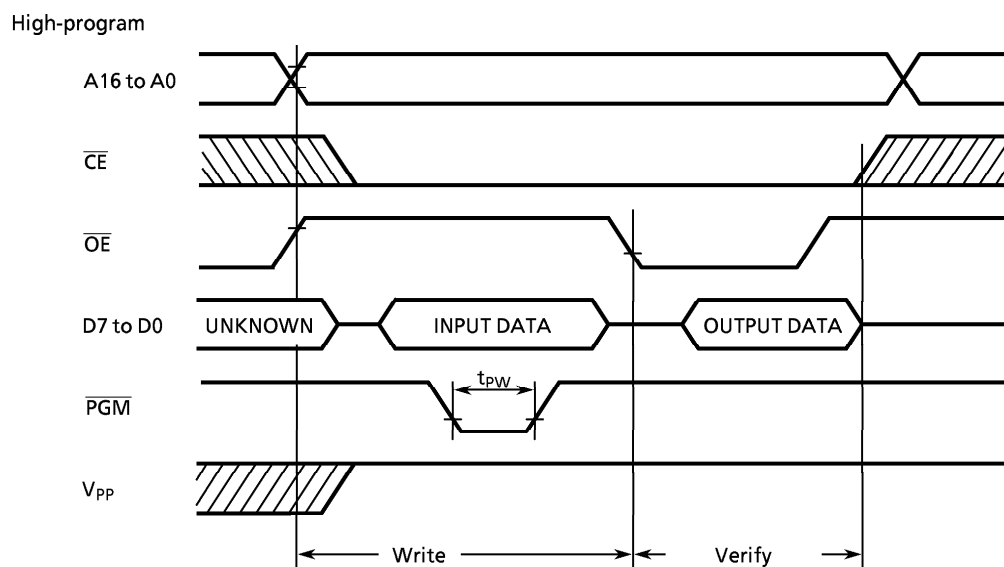
Note: An electrical shield by metal shield plate on the IC package should be recommended in order to prevent the device from the high electric field stress applied for continuous reliable operation.

DC/AC Characteristics (PROM mode) ($V_{SS} = 0\text{ V}$)(1) Read Operation ($V_{DD} = 5.0 \pm 0.25\text{ V}$, $T_{opr} = 25 \pm 5^\circ\text{C}$)

Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
Input High Voltage (A0 to A16, \overline{CE} , \overline{OE} , \overline{PGM})	V_{IH4}		$V_{DD} \times 0.7$	–	V_{DD}	V
Input Low Voltage (A0 to A16, \overline{CE} , \overline{OE} , \overline{PGM})	V_{IL4}		0	–	0.8	V
Program Power Supply Voltage	V_{PP}		4.75	5.0	5.25	V
Address Access Time	t_{ACC}		–	$1.5tcyc + 300$	–	ns

Note : $tcyc = 500\text{ ns}$ at 8 MHz(2) High-Speed Programming Operation ($T_{opr} = 25 \pm 5^\circ\text{C}$, $V_{DD} = 6.25 \pm 0.25\text{ V}$)

Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
Input High Voltage (D0 to D7, A0 to A16, \overline{CE} , \overline{OE} , \overline{PGM})	V_{IH4}		$V_{DD} \times 0.7$	–	V_{DD}	V
Input Low Voltage (D0 to D7, A0 to A16, \overline{CE} , \overline{OE} , \overline{PGM})	V_{IL4}		0	–	0.8	V
Program Power Supply Voltage	V_{PP}		12.5	12.75	13.0	V
Initial Program Pulse Width	t_{PW}	$V_{DD} = 6.0\text{ V}$	0.095	0.1	0.105	ms



Note1: When V_{cc} power supply is turned on or after, V_{pp} must be increased.

When V_{cc} power supply is turned off or before, V_{pp} must be decreased.

Note2: The device must not be set to the EPROM programmer or picked up from it under applying the program voltage ($12.75\text{ V} \pm 0.5\text{ V}$) to the V_{pp} pin as the device is damaged.

Note3: Be sure to execute the recommended programing mode with the recommended programing adaptor. If a mode or an adaptor except the above, the misoperation sometimes occurs.

Typical Characteristics

(Ta = 25°C)

